勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

PNP/NPN Epitaxial Planar Silicon Transistors

# 2SB904/2SD1213



# 30V/12A High-Speed Switching Applications

## **Applications**

 Large current switching of relay drivers, high-speed inverters, converters.

#### **Features**

- $\cdot$  Low collector-to-emitter saturation voltage : VCE(sat)=-0.5V (PNP), 0.4V (NPN) max.
- · Large current capacity.

(): 2SB904

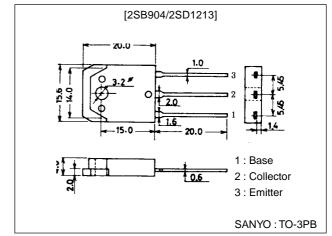
# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

## **Package Dimensions**

unit:mm

2022A



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)60	V
Collector-to-Emitter Voltage	VCEO		(–)30	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(–)6	V
Collector Current	lС		(–)20	Α
Collector Current (Pulse)	ICP		(–)30	Α
Collector Dissipation	PC		2.5	W
		Tc=25°C	60	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(-)0.1	mA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)0.1	mA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)1A	70*		280*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)10A	30			
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)8A, I <sub>B</sub> =(-)0.4A		(-0.25)	(-0.5)	V
				0.2	0.4	V

 $<sup>\</sup>ast$  : The 2SB904/2SD1213 are classified as follows according to  $h_{FE}$  at 1A.

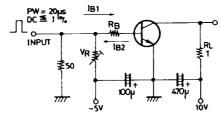
70 Q 140 100 R 200 140 S 280

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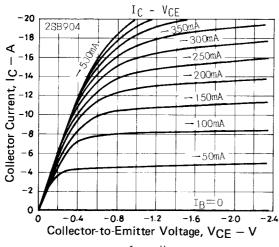
### 2SB904/2SD1213

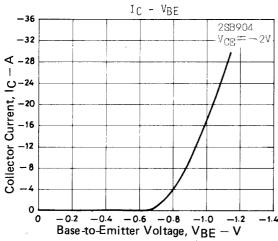
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Oill
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)1A		120		MHz
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)1mA, I <sub>E</sub> =0	(-)60			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-)30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =(-)1mA, I <sub>C</sub> =0	(-)6			V
Turn-ON Time	t <sub>on</sub>	See specified Test Circuit		300		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(300)		ns
				600		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		20		ns

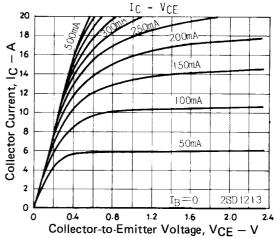
### **Switching Time Test Circuit**

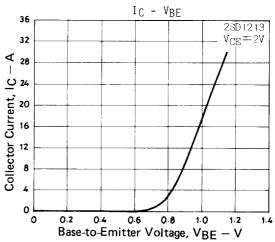


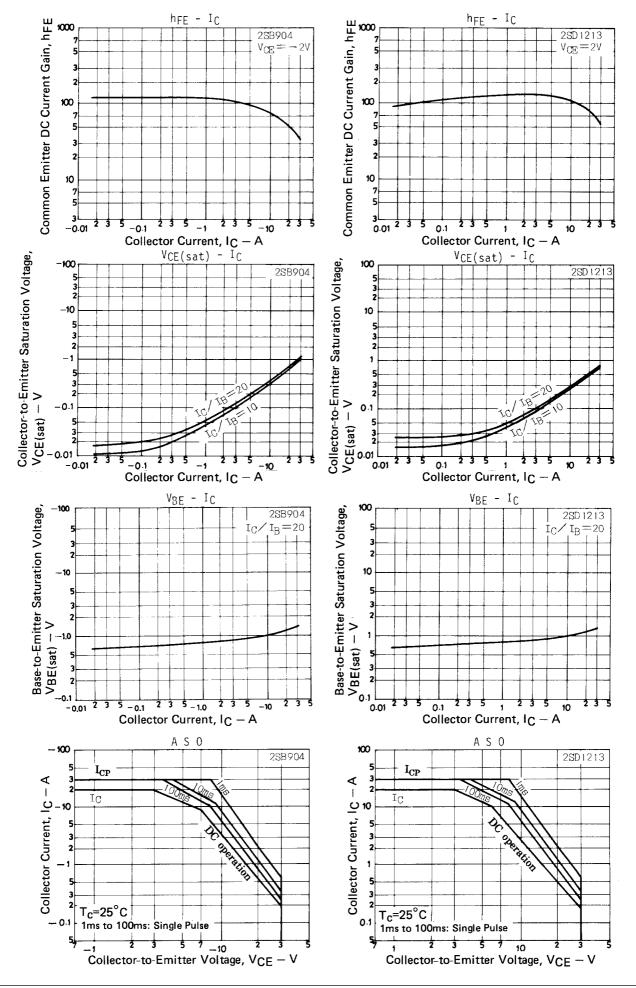
 $20I_{B1} = -20I_{B2} = I_C = 10A$ (For PNP, the polarity is reversed) Unit (resistance:  $\Omega$ , capacitance: F)



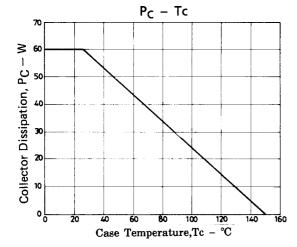








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